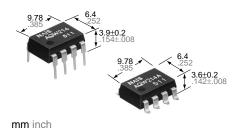




# GU (General Use) Type [2-Channel (Form A) Type]

# PhotoMOS RELAYS



### 3 6 4 1 5

# **FEATURES**

#### 1. Compact 8-pin DIP size

The device comes in a compact (W)  $6.4 \times$  (L)  $9.78 \times$ (H) 3.9 mm (W)  $.252 \times$ (L)  $.385 \times$ (H) .154 inch, 8-pin DIP size (through hole terminal type).

- 2. Applicable for 2 Form A use as well as two independent 1 Form A use
- **3. Controls low-level analog signals** PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.
- 4. High sensitivity, high speed response

Can control a maximum 0.13 A load current with a 5 mA input current. Fast operation speed of 310  $\mu$ s (typical). (AQW214)

#### 5. Low-level off state leakage current

The SSR has an off state leakage current of several milliamperes whereas the PhotoMOS relays has only 100 pA even with the rated load voltage of 400 V (AQW214).

- 6. Low-level thermal electromotive force (Approx. 1  $\mu\text{V})$
- 7. Eliminates the need for a counter electromotive force protection diode in the drive circuits on the input side
- 8. Stable ON resistance.
- 9. Eliminates the need for a power supply to drive the power MOSFET

#### TYPICAL APPLICATIONS

- High-speed inspection machines
- Telephones equipment
- Computer

#### **TYPES**

## 1. AC/DC type

			Par	Packing quantity			
Output rating*		Through hole terminal	S			urface-mount termir	
Load voltage	Load current	Tube pac	ing style Tape and reel packing style			Tube	Tape and reel
60V	350 mA	AQW212	AQW212A	AQW212AX	AQW212AZ		1,000 pcs.
100 V	300 mA	AQW215	AQW215A	AQW215AX	AQW215AZ	1 tube contains	
200 V	160 mA	AQW217	AQW217A	AQW217AX	AQW217AZ	40 pcs.	
350 V	120 mA	AQW210	AQW210A	AQW210AX	AQW210AZ	1 batch contains	
400 V	100 mA	AQW214	AQW214A	AQW214AX	AQW214AZ	400 pcs.	
600 V	40 mA	AQW216	AQW216A	AQW216AX	AQW216AZ		

<sup>\*</sup>Indicate the peak AC and DC values.

Note: For space reasons, the package type indicator "X" and "Z" are omitted from the seal.

## **RATING**

#### 1. AC/DC type

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQW212(A)	AQW215(A)	AQW217(A)	AQW210(A)	AQW214(A)	AQW216(A)	Remarks
Input	LED forward curre	nt I <sub>F</sub>	50 mA						
	LED reverse volta	ge V <sub>R</sub>			3				
	Peak forward curr	ent I <sub>FP</sub>			f = 100 Hz, Duty factor = 0.1%				
	Power dissipation	Pin							
Output	Load voltage (peak AC)	VL	60 V	100 V	200 V	350 V	400 V	600 V	
	Continuous load current	IL	0.35 A (0.40A)	0.30 A (0.35 A)	0.16 A (0.2 A)	0.12 A (0.14 A)	0.10 A (0.13 A)	0.04 A (0.05 A)	( ): in case of using only 1 channel A connection: Peak AC, DC
	Peak load current	<b>I</b> peak	1.0 A	0.9 A	0.48 A	0.36 A	0.3 A	0.12 A	A connection: 100 ms (1 shot), V <sub>L</sub> = DC
	Power dissipation Pout			•					
Total power dissipation		Рт							
I/O isolation voltage		Viso			Between input and output/ between contact sets				
Temperalimits	ature Operatir	g T <sub>opr</sub>		-40°	Non-condensing at low temperatures				
IIIIIII	Storage	Tstg		-40°					

# AQW21O

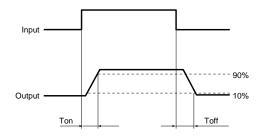
2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	AQW212(A)	AQW215(A)	AQW217(A)	AQW210(A)	AQW214(A)	AQW216(A)	Condition
Input	LED operate current	Typical	-		IL = Max.   IL = Max.   IF = 5 mA   IF = 5 mA   IL = Max.   Within 1 son time   IF = 0   VL = Max.   IF = 5 mA   IL = Max.					
		Maximum	Fon							
	LED turn off current	Minimum	Foff		I. – Mov					
		Typical	IFoff		IL = IVIAX.					
	LED dropout voltage	Typical	VF		IL = Max.   IF = 5 mA   IL = Max.   Within 1 son time   IF = 0   VL = Max.   IF = 5 mA   IL = Max.   IF = 5 mA   IL = Max.   IF = 1 max.   I					
		Maximum	\ \rac{\rac{\rac{\rac{\rac{\rac{\rac{							
Output	On resistance	Typical	Ron	0.83 Ω	2.3 Ω	11 Ω	23 Ω	30 Ω	70 Ω	-
		Maximum		2.5 Ω	4.0 Ω	15 Ω	35 Ω	50 Ω	120 Ω	
	Off state leakage current	Maximum	I <sub>Leak</sub>							
Transfer characteristics	Turn on time*	Typical	Ton	0.65 ms	0.60 ms	0.25 ms	0.25 ms	0.31 ms	0.28 ms	-
		Maximum		2 ms	2 ms	1.0 ms	0.5 ms	0.5 ms	0.5 ms	
	Turn off time*	Typical	Toff	0.08 ms	0.06 ms	0.05 ms	0.05 ms	0.05 ms	0.04 ms	I <sub>F</sub> = 5 mA
		Maximum	l off		I∟ = Max.					
	I/O capacitance	Typical			f = 1 MHz					
		Maximum	Ciso	1.5 pF						V <sub>B</sub> = 0
	Initial I/C isolation resistance	Minimum	Riso	1,000 ΜΩ						500 V DC

Note: Recommendable LED forward current IF = 5mA.

For type of connection, see page 32.



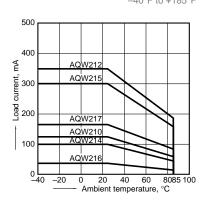


- **■** For Dimensions, see Page 27.
- For Schematic and Wiring Diagrams, see Page 32.
- **■** For Cautions for Use, see Page 36.

# REFERENCE DATA

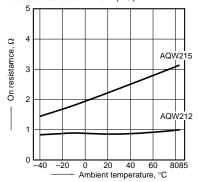
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F



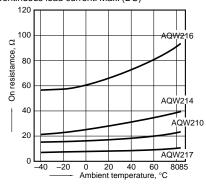
2.-(1) On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



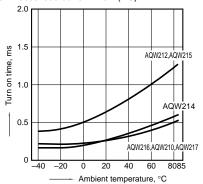
2.-(2) On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



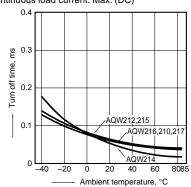
3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



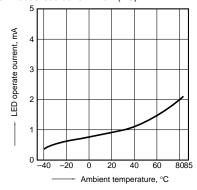
4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



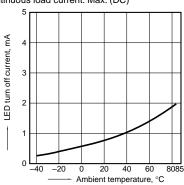
5. LED operate current vs. ambient tempera ture characteristics

Sample: All types; Load voltage: Max. (DC); Continuous load current: Max. (DC)



6. LED turn off current vs. ambient temperature characteristics

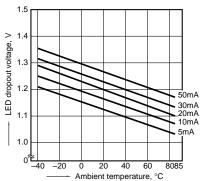
Sample: All types; Load voltage: Max. (DC); Continuous load current: Max. (DC)



7. LED dropout voltage vs. ambient temperature characteristics

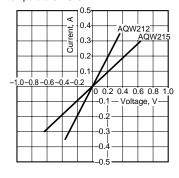
Sample: All types;

LED current: 5 to 50 mA



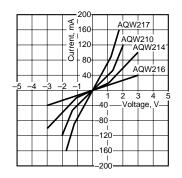
8.-(1) Voltage vs. current characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



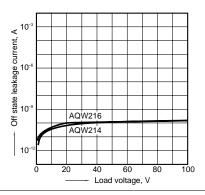
8.-(2) Voltage vs. current characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



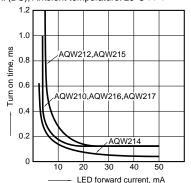
9. Off state leakage current

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



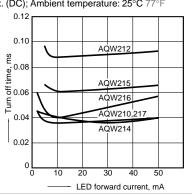
10. LED forward current vs. turn on time characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



11. LED forward current vs. turn off time characteristics

Measured portion: between terminals 5 and 6, 7 and 8: Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



12. Applied voltage vs. output capacitance characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Frequency: 1 MHz;

Ambient temperature: 25°C 77°F

